PU3114, PU4114, PU4414

Silicon NPN Epitaxial Planar Type

Power Amplifier, Switching Complementary Pair with PU3214, PU4214, PU4514

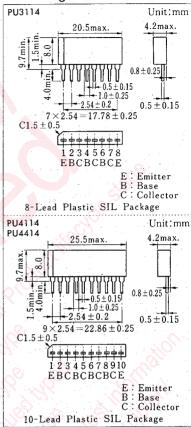
■ Features

- Low collector-emitter saturation voltage (V_{CE(sat)})
- High speed switching
- Good linearity of DC current gain (hFE)
- High collector current (Ic)
- PU3114: 3 NPN elements
- PU4114: 4 NPN elements
- PU4114: 2 NPN elements × 2 (4 elements in total)

■ Absolute Maximum Ratings (Tc=25°C)

Item	Symbol	Value	Unit
Collector-base voltage	V _{CBO}	40	V
Collector-emitter voltage	V_{CEO}	20	V
Emitter-base voltage	V _{EBO}	5	V
Peak collector current	I_{CP}	12	Α.
Collector current	$I_{\rm C}$	7	A
Power dissipation	P_{D}	15	w
Junction temperature	$T_{\rm j}$	`150	S C
Storage temperature	$T_{ m stg}$	-55~+150	c c

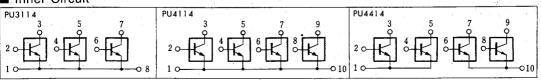
■ Package Dimensions

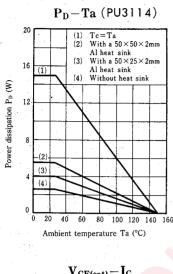


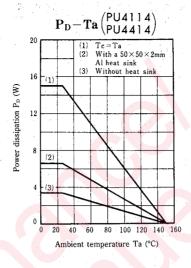
■ Electrical Characteristics (Tc=25°C)

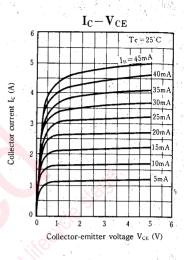
Item	Symbol	Condition	min.	typ.	max.	Unit
Collector cutoff current	I_{CBO}	$V_{CB} = 40V, I_E = 0$			50	μA
Emitter cutoff current	I _{EBO}	$V_{EB}=5V$, $I_C=0$	10		50	μΑ
Collector-emitter voltage	V_{CEO}	$I_C = 10 \text{mA}, I_B = 0$	20.	7.7		V
DC current gain	h _{FE1}	$V_{CE} = 2V, I_C = 0.1A$	45			
	h _{FE2}	$V_{CE}=2V$, $I_{C}=2A$	60	. :	260	
Collector-emitter saturation voltage	V _{CE} (sat)	$I_C = 5A$, $I_B = 0.16A$	50		0.6	V
Base-emitter saturation voltage	V _{BE} (sat)	$I_C = 5A$, $I_B = 0.16A$		11	1.5	V
Transition frequency	f _T	$V_{CE} = 10V$, $I_C = 0.5A$, $f = 10MHz$	-	150		MHz
Collector output capacitance	C_{ob}	$V_{CB} = 10V, I_E = 0, f = 1MHz$	*	110		pF
Turn-on time	ton	180 100		0.3		μs
Storage time	t _{stg}	$I_C = 2A$, $I_{B1} = 66 \text{mA}$, $I_{B2} = -66 \text{mA}$		0.3		μs
Fall time	tf			0.1		μs

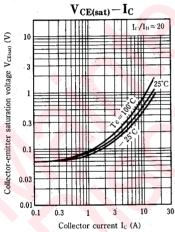
■ Inner Circuit

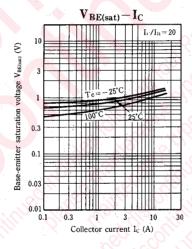


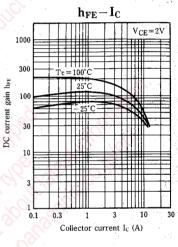


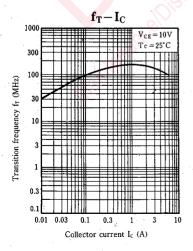


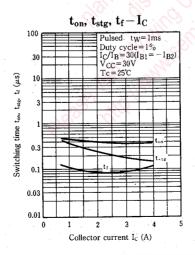


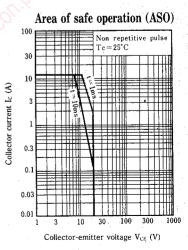












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